Written Test for Degree Engineering Interview

Date: 20/07/2024 Time:1 hr Marks:20

Note: All questions are carry equal marks

1. If silicon diode is operating in forward bias in a circuit with 12 V supply and 240  $\Omega$  series resistance, then what is the voltage drop across the diode.

A. 1.5 V B. 0.4 V C. 1.1 V D. 0.7 V

- 2. In feedback control system shown in Figure 1 below  $G(s) = \frac{6}{s(s+1)(s+2)}$ , where R(s), Y(s), &E(s) are Laplace transform of r(t), y(t), &e(t) respectively, if the input r(t) is a unit ramp function then
  - A.  $\lim_{t \to \infty} e(t) = 0$  B.  $\lim_{t \to \infty} e(t) = \frac{1}{3}$  C.  $\lim_{t \to \infty} e(t) = \frac{1}{4}$  D.  $\lim_{t \to \infty} e(t)$  does not exist, e(t)

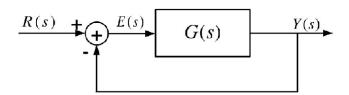


Figure 1: Q.No.2

is oscillatory.

3. What is the z-transform of the following finite duration signal?  $x[n] = \{2,4,5,7,0,1\}$ 

A. 
$$2+4z+5z^2+7z^3+z^4$$
 B.  $2+4z+5z^2+7z^3+z^5$  C.  $2+4z^{-1}+5z^{-2}+7z^{-3}+z^{-5}$  D.  $2z^2+4z+5+7z^{-1}+z^{-3}$ 

- 4. The BJT as a switch is is operated in one of the following: A. Only saturation region B. Active region C. Only cut off region D. Both saturation and cut off region
- 5. A DC power supply has no load voltage of 30 V and full load voltage of 25 V at full load current of 1 A. Its output resistance and load regulation respectively are.

A.  $5\Omega$  and 20% B.  $25\Omega$  and 20% C.  $5\Omega$  and 16.7% D.  $25\Omega$  and 16.7%

- 6. A 500 W carrier signal is amplitude modulated modulation percentage of 60%. The total power in the modulated signal if the form amplitude modulation used is the double sideband AM with full carrier(A3E).
  - A. 590 W B. 534 W C. 125 W D. 300 W

7. What will be the o/p of the given logic gate of Figure 2?

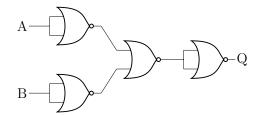


Figure 2: Q.No.7

C. AND A. NOR B. NAND D. OR

- 8. Let  $\hat{i}$  and  $\hat{j}$  be the unit vectors along x and y axes respectively, and let A be the positive constant. Which one of the following is true for vector fields  $\bar{F}_1 = A(\hat{i}y + \hat{j}x), \bar{F}_2 = A(\hat{i}y - \hat{j}x)$ 
  - A. Both  $\bar{F}_1$  and  $\bar{F}_2$  are electrostatic fields. B. Only  $\bar{F}_1$  is an electrostatic fields. C. Only  $\bar{F}_2$  is an electrostatic fields. D. Neither  $\bar{F}_1$  nor  $\bar{F}_2$  are electrostatic fields.
- 9. The current  $I_y$  flowing through  $660\Omega$  resistance is (Refer Figure 3):

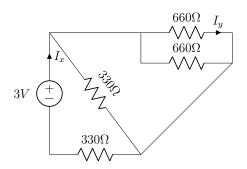


Figure 3: Q.No.9

A.  $I_x$  B.  $I_x/2$  C.  $I_x/4$  D.  $I_x/3$ 

10. In the circuit shown below, P and Q are the inputs. The logical function realized by the circuit shown Figure 4 below is:

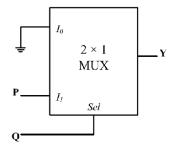


Figure 4: Q.No.10

A. 
$$Y = PQ$$
 B.  $Y = P + Q$  C.  $Y = \overline{PQ}$  D.  $Y = \overline{P + Q}$